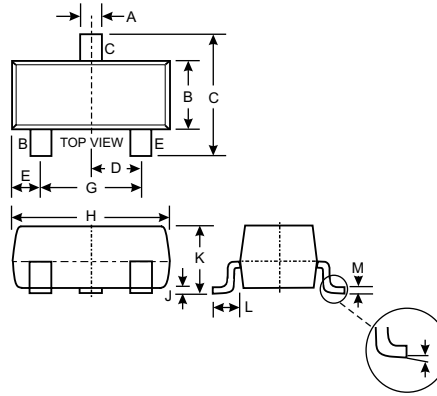


### Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types Available (BC856-BC858)
- For Switching and AF Amplifier Applications

### Mechanical Data

- Case: SOT-23, Molded Plastic
- Case material - UL Flammability Rating Classification 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Pin Connections: See Diagram
- Marking Codes (See Table Below & Diagram on Page 3)
- Ordering & Date Code Information: See Page 3
- Approx. Weight: 0.008 grams



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.85	0.80
$\alpha$	0°	8°
All Dimensions in mm		

Marking Code (Note 2)			
Type	Marking	Type	Marking
BC846A	1A, K1Q	BC847C	1G, K1M
BC846B	1B, K1R	BC848A	1J, K1J, K1E, K1Q
BC847A	1E, K1E, K1Q	BC848B	1K, K1K, K1F, K1R
BC847B	1F, K1F, K1R	BC848C	1L, K1L, K1M

### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	BC846 BC847 BC848 V <sub>CBO</sub>	80 50 30	V
Collector-Emitter Voltage	BC846 BC847 BC848 V <sub>CEO</sub>	65 45 30	V
Emitter-Base Voltage	BC846, BC847 BC848 V <sub>EBO</sub>	6.0 5.0	V
Collector Current	I <sub>C</sub>	100	mA
Peak Collector Current	I <sub>CM</sub>	200	mA
Peak Emitter Current	I <sub>EM</sub>	200	mA
Power Dissipation (Note 1)	P <sub>d</sub>	300	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R <sub>θJA</sub>	417	°C/W
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-65 to +150	°C

- Notes:
1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>
  2. Current gain subgroup "C" is not available for BC846.

**Electrical Characteristics** @  $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage (Note 3)	BC846 BC847 BC848	$V_{(BR)CBO}$	80 50 30	— — —	— — —	V	$I_C = 10\mu\text{A}, I_B = 0$
Collector-Emitter Breakdown Voltage (Note 3)	BC846 BC847 BC848	$V_{(BR)CEO}$	65 45 30	— — —	— — —	V	$I_C = 10\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage (Note 3)	BC846, BC847 BC848	$V_{(BR)EBO}$	6 5	—	—	V	$I_E = 1\mu\text{A}, I_C = 0$
H-Parameters							
Small Signal Current Gain	Current Gain Group A B C	$h_{fe}$	— — —	220 330 600	— — —	— — —	$V_{CE} = 5.0\text{V}, I_C = 2.0\text{mA},$ $f = 1.0\text{kHz}$
Input Impedance	Current Gain Group A B C	$h_{ie}$	— — —	2.7 4.5 8.7	— — —	$k\Omega$ $k\Omega$ $k\Omega$	
Output Admittance	Current Gain Group A B C	$h_{oe}$	— — —	18 30 60	— — —	$\mu\text{S}$ $\mu\text{S}$ $\mu\text{S}$	
Reverse Voltage Transfer Ratio	A	$h_{re}$	—	$1.5 \times 10^{-4}$	—	—	
Current Gain Group	B	$h_{re}$	—	$2 \times 10^{-4}$	—	—	
	C	$h_{re}$	—	$3 \times 10^{-4}$	—	—	
DC Current Gain	Current Gain Group A B C (Note 3)	$h_{FE}$	110 200 420	180 290 520	220 450 800	—	$V_{CE} = 5.0\text{V}, I_C = 2.0\text{mA}$
Collector-Emitter Saturation Voltage (Note 3)		$V_{CE(SAT)}$	—	90 200	250 600	mV	$I_C = 10\text{mA}, I_B = 0.5\text{mA}$ $I_C = 100\text{mA}, I_B = 5.0\text{mA}$
Base-Emitter Saturation Voltage (Note 3)		$V_{BE(SAT)}$	—	700 900	—	mV	$I_C = 10\text{mA}, I_B = 0.5\text{mA}$ $I_C = 100\text{mA}, I_B = 5.0\text{mA}$
Base-Emitter Voltage (Note 3)		$V_{BE(ON)}$	580 —	660 —	700 770	mV	$V_{CE} = 5.0\text{V}, I_C = 2.0\text{mA}$ $V_{CE} = 5.0\text{V}, I_C = 10\text{mA}$
Collector-Cutoff Current (Note 3)	BC846 BC847 BC848	$I_{CES}$	— — —	— — —	15 15 15	nA nA nA	$V_{CE} = 80\text{V}$ $V_{CE} = 50\text{V}$ $V_{CE} = 30\text{V}$ $V_{CB} = 40\text{V}$ $V_{CB} = 30\text{V}, T_A = 150^\circ\text{C}$
		$I_{CBO}$	— —	— —	15 5.0	nA $\mu\text{A}$	
Gain Bandwidth Product		$f_T$	100	300	—	MHz	$V_{CE} = 5.0\text{V}, I_C = 10\text{mA},$ $f = 100\text{MHz}$
Collector-Base Capacitance		$C_{CBO}$	—	3.0	—	pF	$V_{CB} = 10\text{V}, f = 1.0\text{MHz}$
Noise Figure		NF	—	2	10	dB	$V_{CE} = 5\text{V}, I_C = 200\mu\text{A},$ $R_S = 2.0k\Omega,$ $f = 1.0\text{kHz}, \Delta f = 200\text{Hz}$

Notes: 3. Short duration pulse test used to minimize self-heating effect.

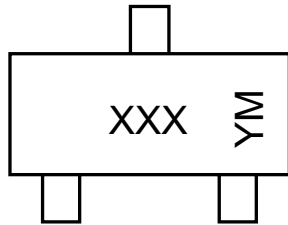
## Ordering Information (Note 4)

Device	Packaging	Shipping
BC84xx-7*	SOT-23	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

\* xx = device type, e.g. BC846A-7.

## Marking Information



XXX = Product Type Marking Code (See Page 1), e.g. K1Q or 1A = BC846A  
YM = Date Code Marking  
Y = Year ex: N = 2002  
M = Month ex: 9 = September

### Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004
Code	J	K	L	M	N	P	R

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D